

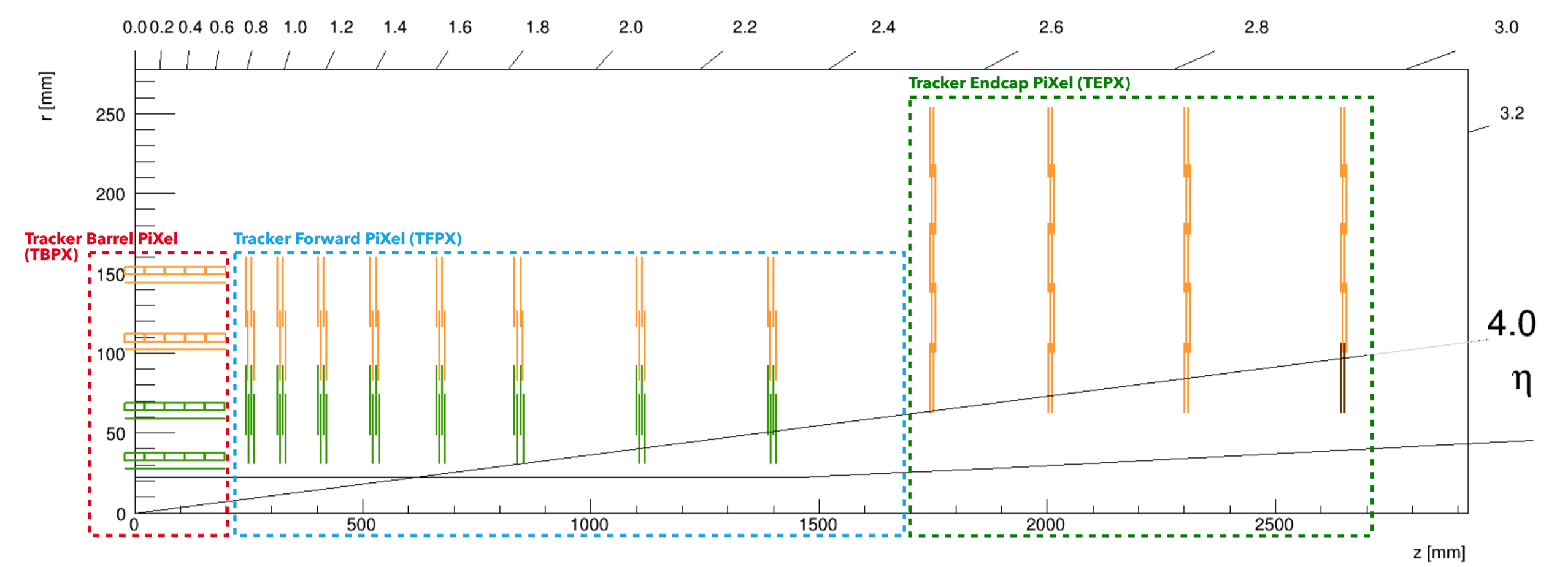
# TEST BEAM RESULTS OF IRRADIATED MODULES FOR THE CMS PHASE 2 UPGRADE EQUIPPED WITH HPK PLANAR PIXEL SENSORS AND RD53B-CMS READOUT CHIPS

## The new CMS Inner Tracker for the Phase 2 Upgrade

For the High-Luminosity phase of the Large Hadron Collider (HL-LHC) at CERN, the Inner Tracker (IT) system of the Compact Muon Solenoid (CMS) experiment will be entirely upgraded [1].

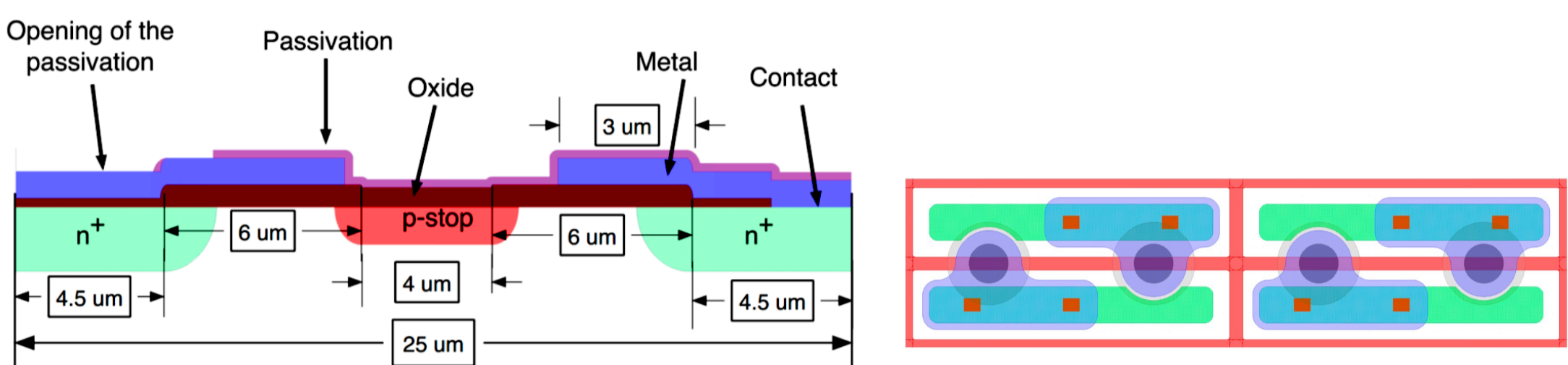
### Key points:

- ▶ Luminosity of  $7.5 \times 10^{34} \text{ cm}^{-2}\text{s}^{-1}$ , with an **integrated luminosity of  $4000 \text{ fb}^{-1}$**  (10 times higher than Phase 1)
- ▶ High radiation tolerance required:
  - ▶ **RD53B-CMS** validated up to  $\Phi_{\text{eq}} = 2.0 \times 10^{16} \text{ cm}^{-2}$  (dose of  $\sim 10 \text{ MGy}$ )
  - ▶ Planar sensors (3Ds for layer 1 of the barrel) with active thickness of  **$150 \mu\text{m}$**  (from  $285 \mu\text{m}$ )
- ▶ Pile-up of  **$\langle \mu \rangle = 200$**  (5 times higher than Phase 1)
  - ▶ Pixel size reduced to  **$25 \times 100 \mu\text{m}^2$**  (from  $100 \times 150 \mu\text{m}^2$ ): occupancy  $< 10^{-4}$  and no cluster merging
- ▶ Only two types of **hybrid pixel modules**: system complexity reduced and flexible management of spares
  - ▶ **1156**  $1 \times 2$  pixel modules ( $\sim 1.8 \times 4.4 \text{ cm}^2$ ): two readout chips per module
  - ▶ **2736**  $2 \times 2$  pixel modules ( $\sim 3.7 \times 4.4 \text{ cm}^2$ ): four readout chips per module



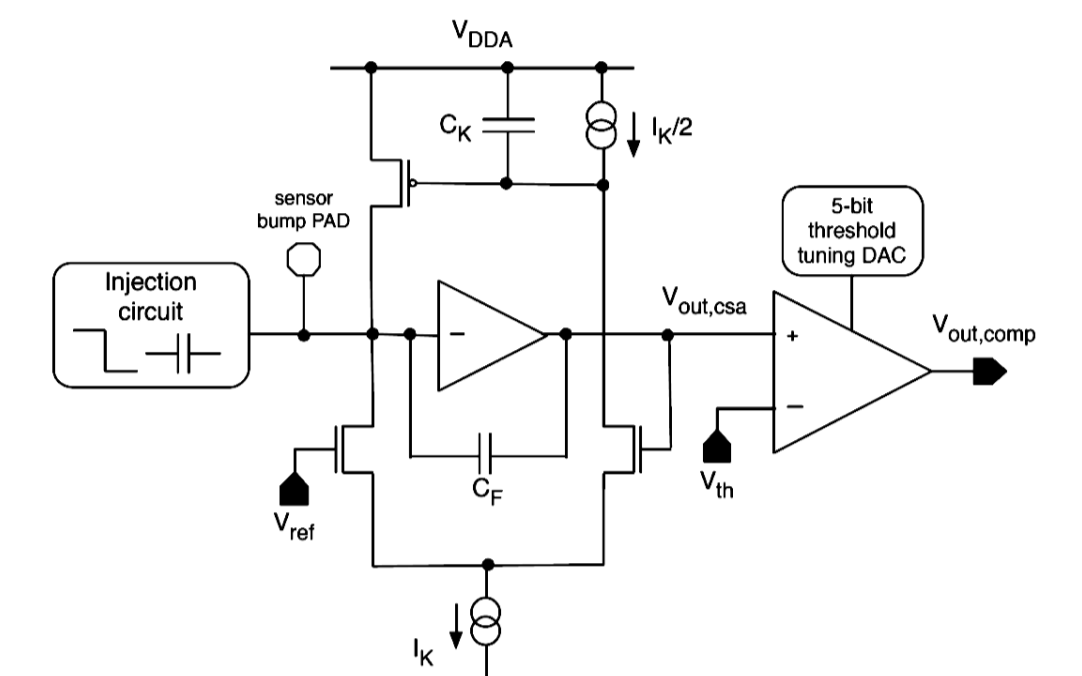
## Planar sensors

- ▶  **$n^+$ -in-p** Hamamatsu Photonics (HPK) planar sensors
- ▶ Inter-chip regions with **big pixels** (for both  $1 \times 2$  and  $2 \times 2$  pixel modules)
- ▶ **No punch through bias dots**: single hit efficiency maximized
- ▶ **Parylene coating**: spark protection
- ▶ Special **"bitten"** design: no  $n^+$  implant under metal (reduced crosstalk)



## RD53B-CMS readout chips

- ▶ Charge digitization through a **4-bit Time-over-Threshold (ToT)** counter at 40 MHz
- ▶ Adjustable **online threshold** below  **$1000 e^-$**
- ▶ **Full size chip**:  $432 \times 336$  pixels ( $21.6 \times 18.6 \text{ mm}^2$ )
- ▶  **$50 \times 50 \mu\text{m}^2$**  pixel pitch
- ▶ Radiation hard design: **65 nm CMOS technology** (TSMC)
- ▶ Improved version of the RD53A **"linear"** front-end (FE) [2]
  - ▶ **Single stage** FE with Krummenacher feedback
  - ▶ Increased TDAC circuit **dynamic range** (with an extra 5th bit)
  - ▶ Improved **cluster charge estimation** (with dual slope ToT)



## Test beam results

All the measurements for these studies were performed at the DESY II Test Beam facility with an **electron beam of 5.2 GeV**. The modules were **irradiated with 24 GeV/c protons** at Proton Irradiation Facility (PS\_IRRAD CERN).

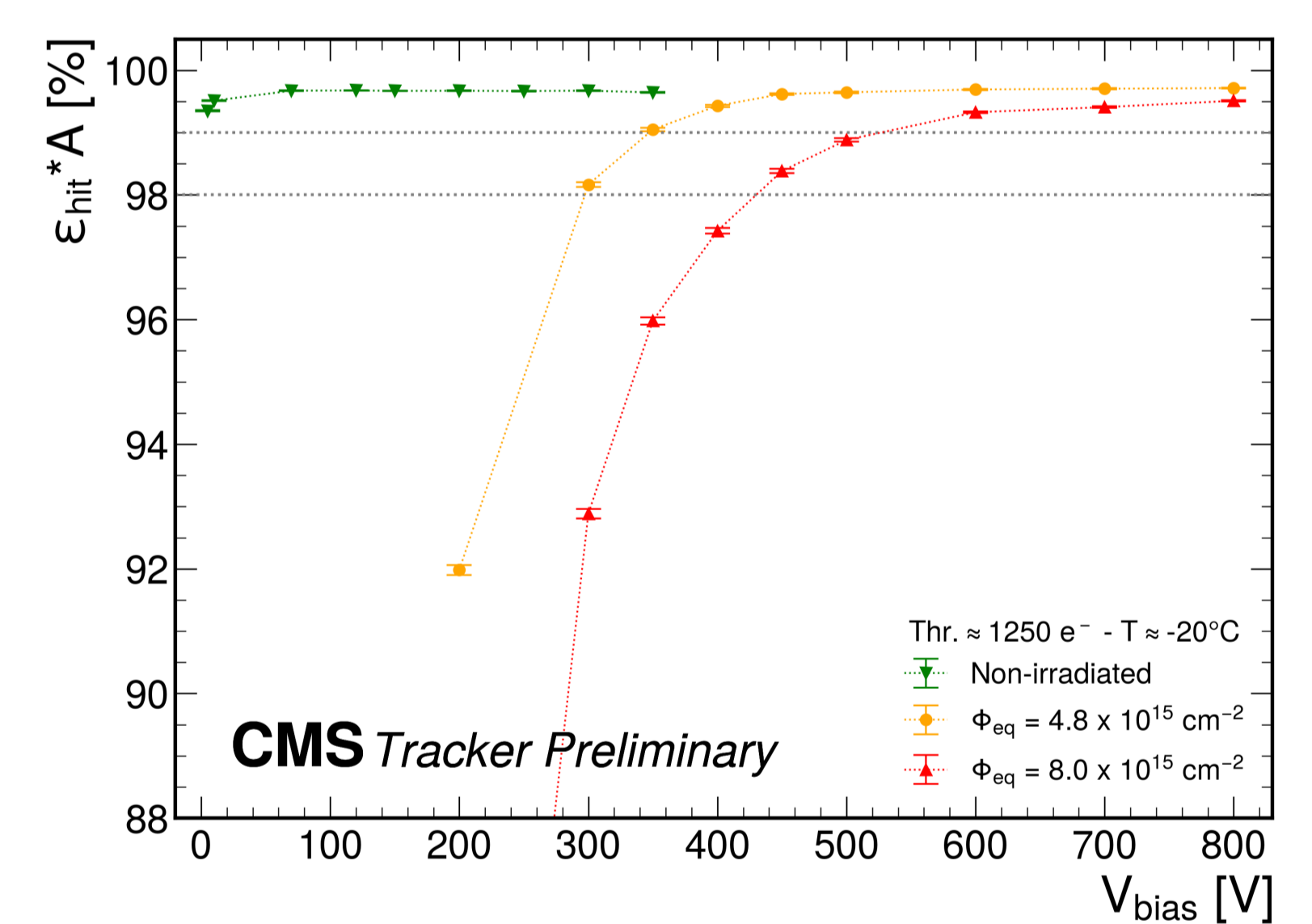
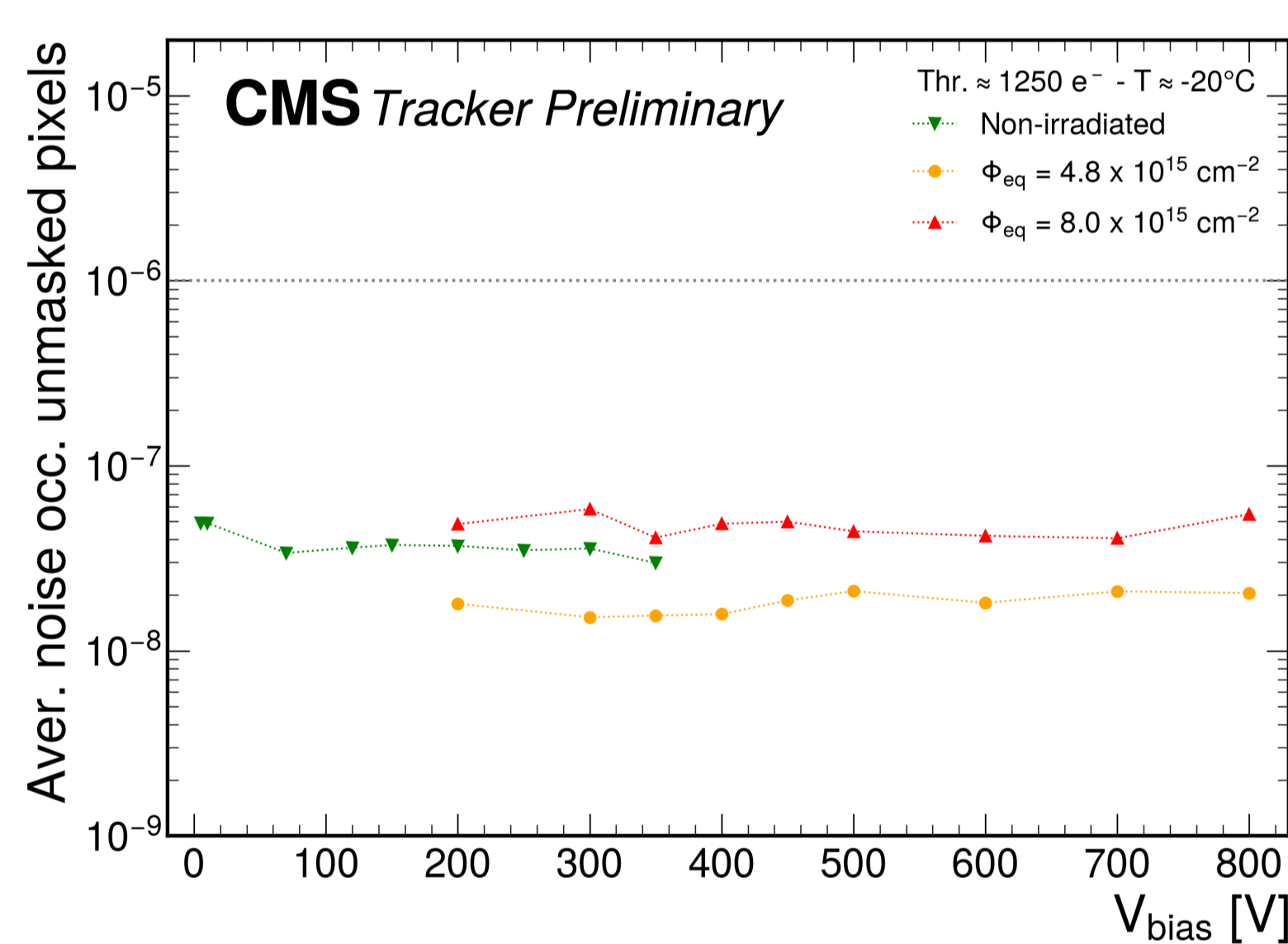
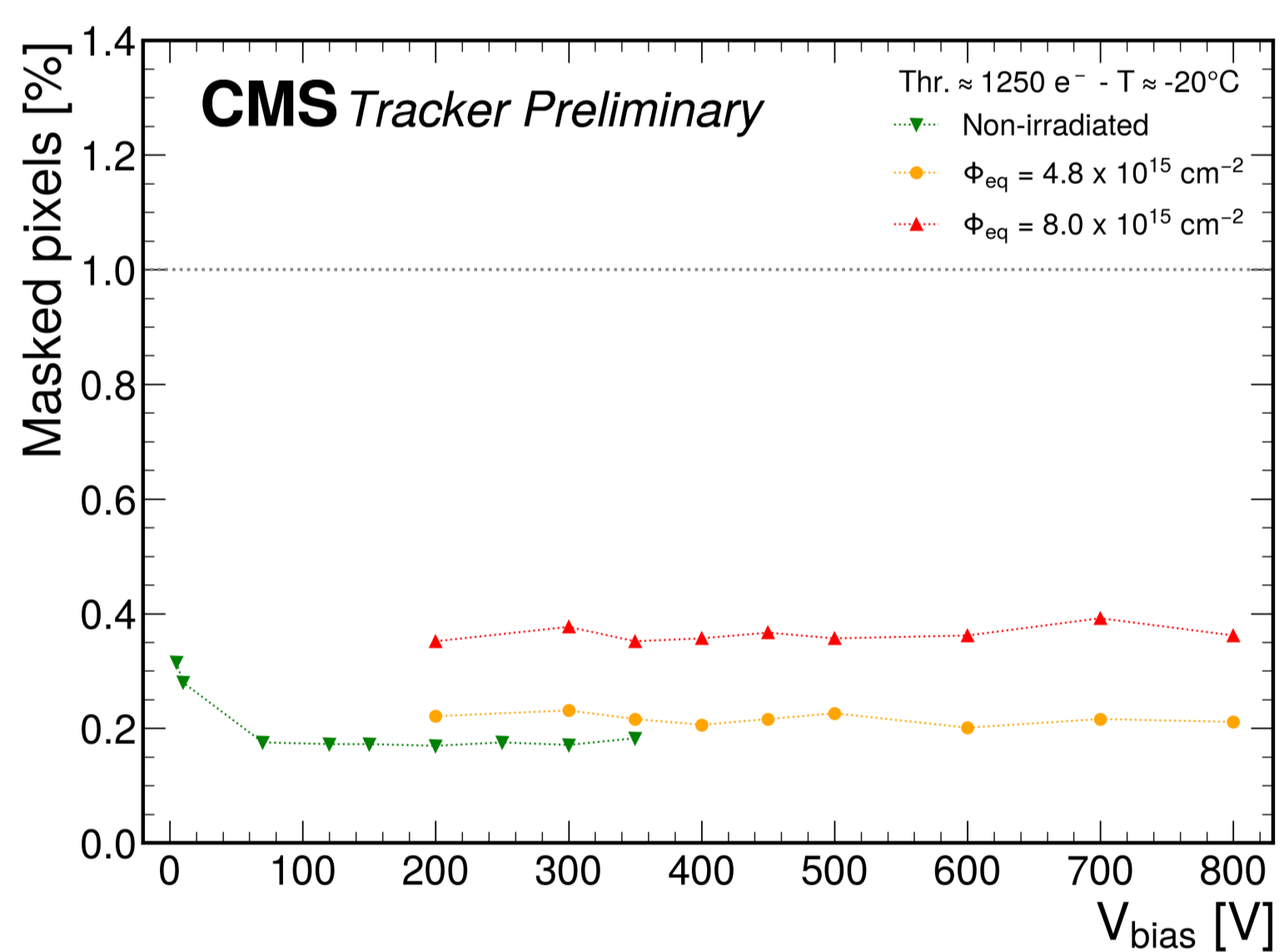
## Single hit efficiency, acceptance and noise

The number of layers of the IT has been optimized to ensure unaffected tracking performance even if data of one layer are missing. The main requirements for every module are:

- ▶ Total number of **masked pixels < 1%** (with an occupancy threshold to classify a pixel as noisy of  $10^{-4}$ )
- ▶ **Average noise occupancy** of the unmasked pixels  **$< 10^{-6}$**
- ▶ At vertical incidence:
  - ▶  $\epsilon_{\text{hit}} * A > 99\%$  **before** and after irradiation to  $\Phi_{\text{eq}} = 0.5 \times 10^{16} \text{ cm}^{-2}$  ( $V_{\text{bias}} \leq 600 \text{ V}$  and  $-20^\circ\text{C}$ )
  - ▶  $\epsilon_{\text{hit}} * A > 98\%$  after irradiation to  $\Phi_{\text{eq}} = 1.0 \times 10^{16} \text{ cm}^{-2}$  ( $V_{\text{bias}} \leq 800 \text{ V}$  and  $-20^\circ\text{C}$ )

$$\epsilon_{\text{hit}} = \frac{N_{\text{tracks}}^{\text{DUT}}}{N_{\text{tracks}}^{\text{total}}}$$

$$A = 1 - \frac{N_{\text{pxl}}^{\text{masked}}}{N_{\text{pxl}}^{\text{total}}}$$

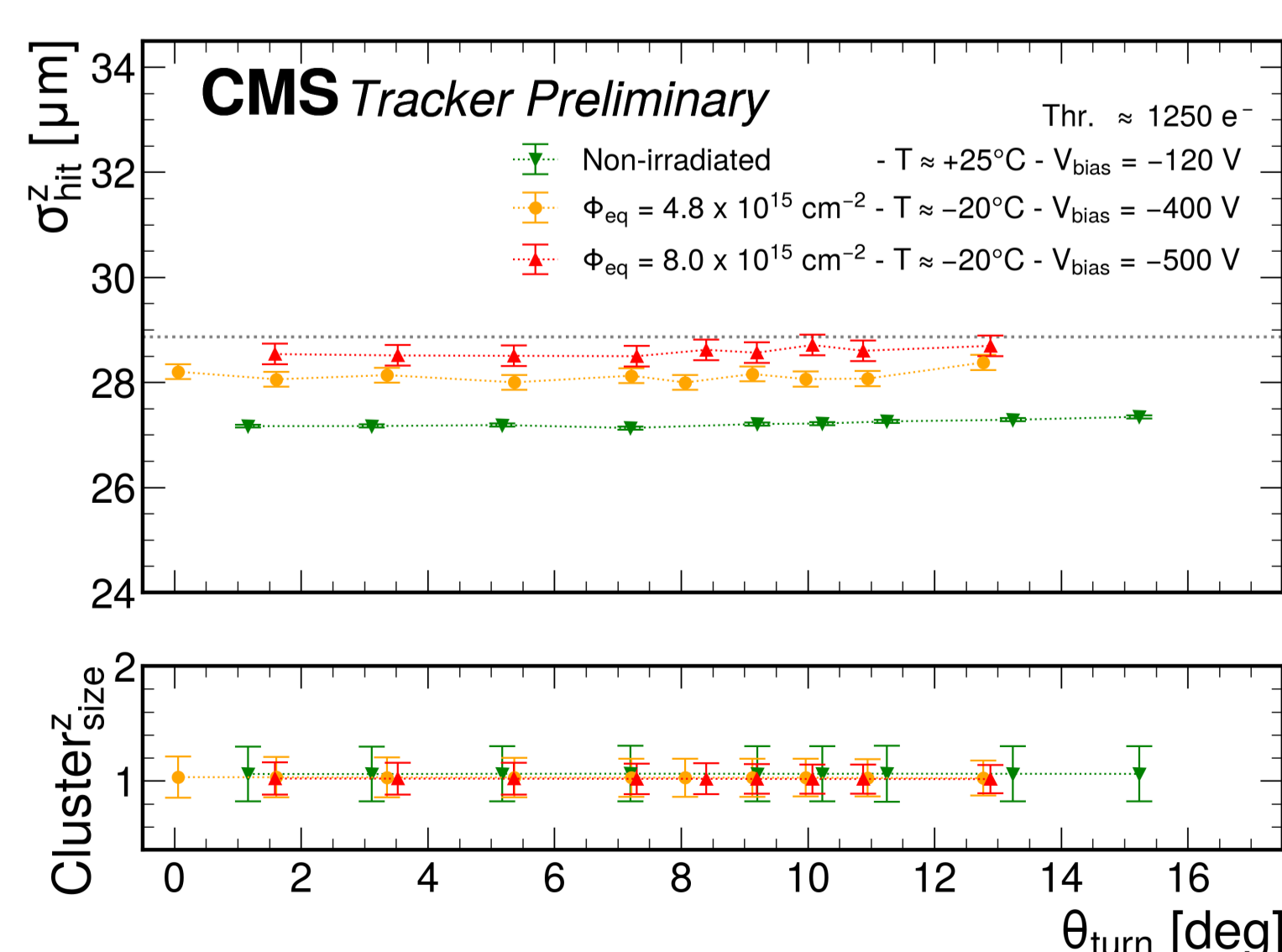
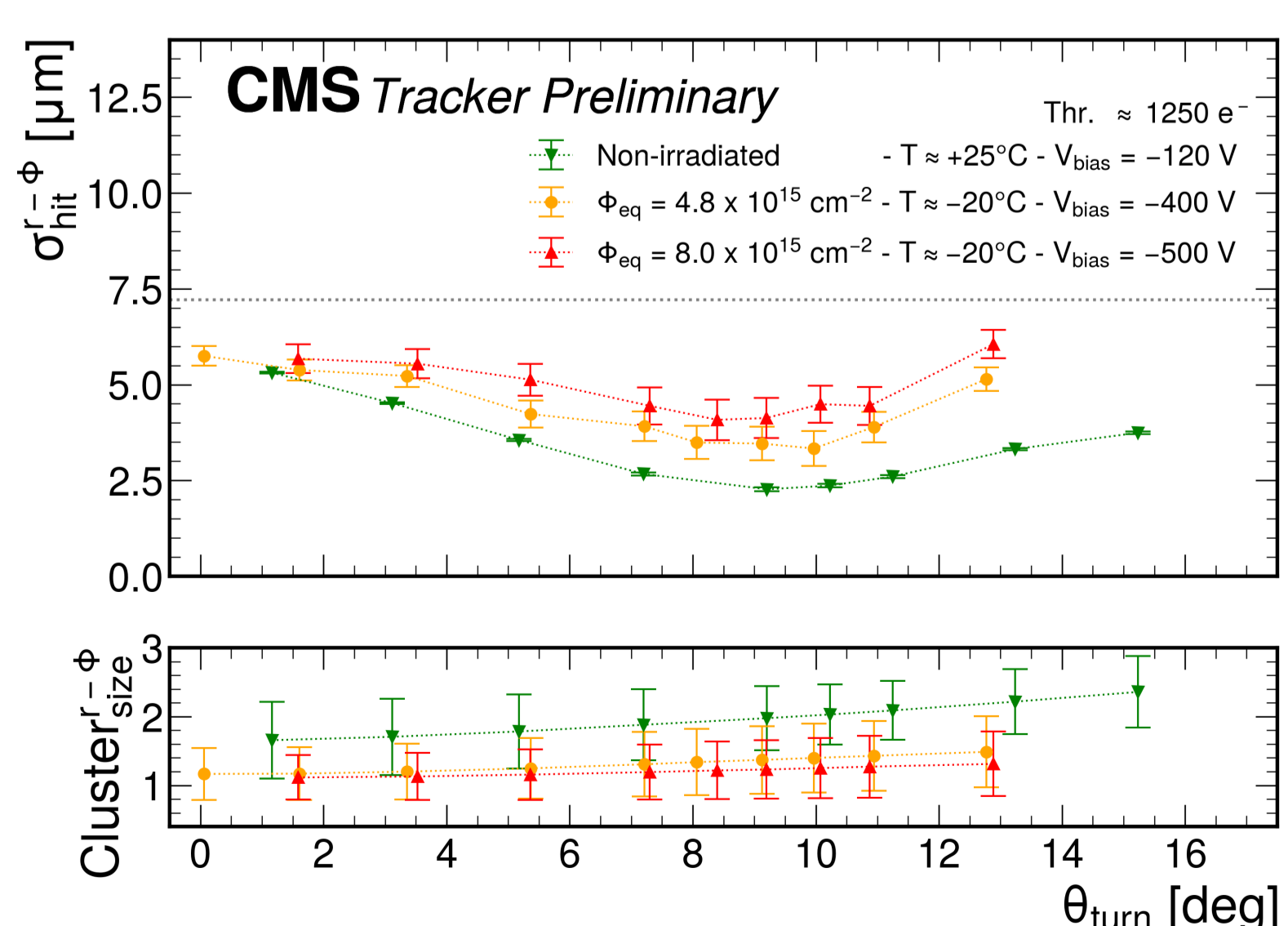


## Single hit spatial resolution

Before irradiation, the single hit spatial resolution ( $\sigma_{\text{hit}}$ ) is better than the binary limit owing to charge sharing and it degrades after irradiation. The aim is to reach a resolution below the binary limit for the full operation time and fluences, meaning  $\sigma_{\text{hit}}^r \sim 7.2 \mu\text{m}$  for the  $r$ - $\phi$  ( $25 \mu\text{m}$  pixel pitch) direction and  $\sigma_{\text{hit}}^z \sim 28.9 \mu\text{m}$  for the  $z$  ( $100 \mu\text{m}$  pixel pitch) direction.

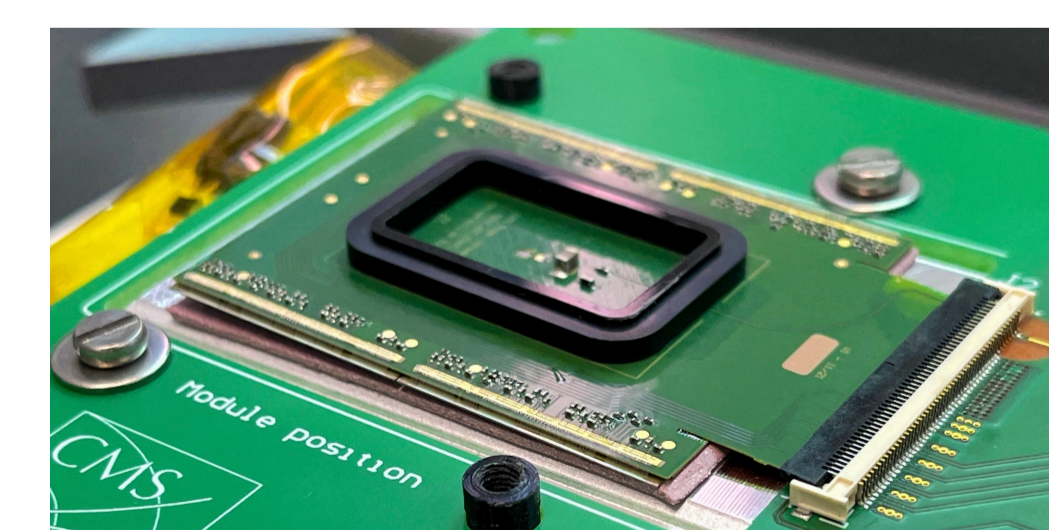
$$\sigma_{\text{hit}} = \sqrt{\sigma_{\text{res}}^2 - \sigma_{\text{tpr}}^2}$$

with:  $\sigma_{\text{res}}$  = truncated RMS from DUT residual distribution [3]  
 $\sigma_{\text{tpr}}$  = truncated RMS from telescope track pointing resolution

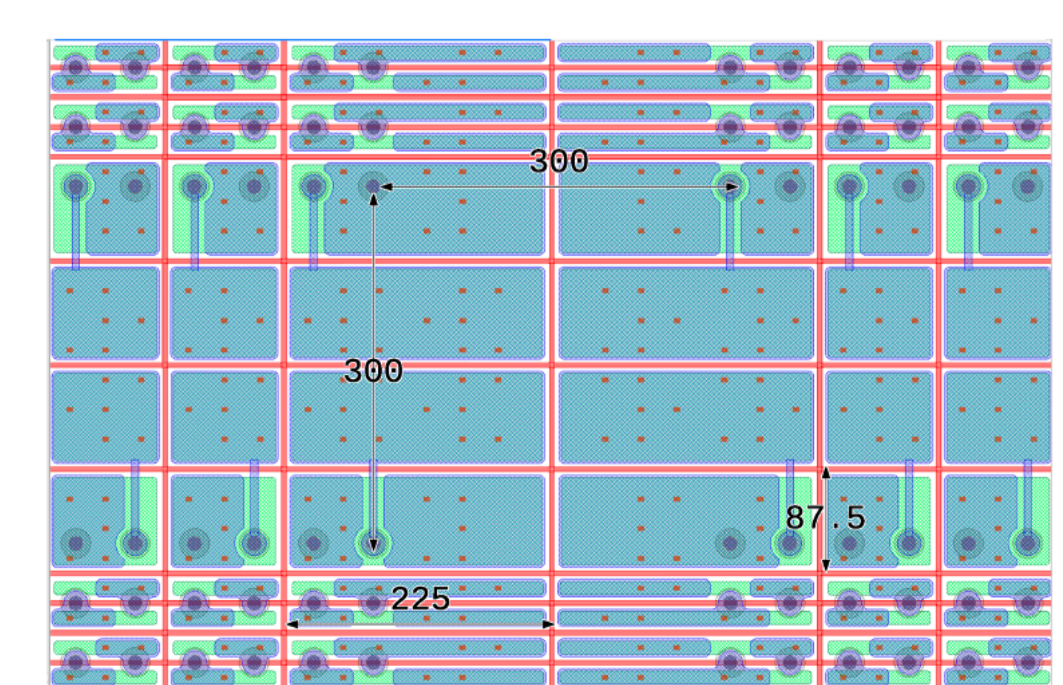


## Validation of a full 2x2 module

- ▶ Non-irradiated and  $\Phi_{\text{eq}} = 0.5 \times 10^{16} \text{ cm}^{-2}$  modules tested: analysis ongoing



- ▶ Focus on the performances of the big pixels in the inter-chip regions



All the requirements of CMS are fulfilled by the modules equipped with planar HPK sensors and single RD53B-CMS readout chips.